



Fast Recovery Diode

DS4147-7 July 2014 (LN31795)

FEATURES

- Double Side Cooling
- High Surge Capability
- Low Recovery Charge

APPLICATIONS

Antiparallel and FWD for GTO

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DF051 25	2500	., ., .,
DF051 24	2400	$V_{RSM} = V_{RRM} + 100V$
DF051 22	2200	
DF051 20	2000	

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DF051 22 for a 2200V device

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order

KEY PARAMETERS

V_{RRM}	2500V
I _{F(AV)}	1490A
I _{FSM}	14000A
Q_r	800μC
t _{rr}	5.0μs

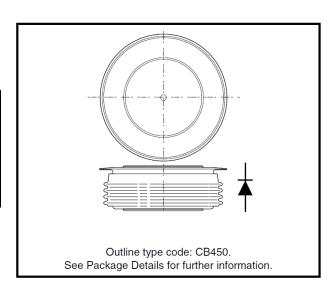


Fig. 1 Package outline



CURRENT RATINGS

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load T _{case} = 65°C	1490	Α			
I _{F(RMS)}	RMS value	T _{case} = 65°C -	2340	Α			
I _F	Continuous (direct) on-state current	T _{case} = 65°C -	2160	Α			
Single Sic	le Cooled (Anode side)						
I _{F(AV)}	Mean forward current	Half wave resistive load T _{case} = 65°C -	995	Α			
I _{F(RMS)}	RMS value	T _{case} = 65°C	1560	Α			
I _F	Continuous (direct) on-state current	T _{case} = 65°C	1390	Α			

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	11.2	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM}$	627	kA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	14.0	kA
l ² t	I ² t for fusing	$V_R = 0$	980	kA ² s

THERMAL AND MECHANICAL RATINGS

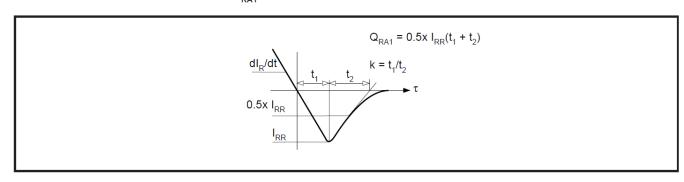
Symbol	Parameter	Test Conditions		Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.018	°C/W
		Single side cooled	Anode DC	-	0.034	°C/W
			Cathode DC	-	0.038	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 8kN	Double side	-	0.003	°C/W
		(with mounting compound)	Single side	-	0.006	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)		-	150	°C
		Reverse (blocking)		-	150	°C
T _{stg}	Storage temperature range			-55	150	°C
F _m	Clamping force			21.0	25.0	kN



CHARACTERISTICS

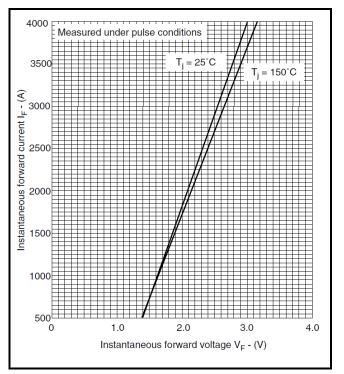
Symbol	Parameter	Test Conditions	Тур.	Max.	Units
V_{FM}	Forward voltage	At 1500A peak, T _{case} = 25°C	-	1.85	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 150°C	-	100	mA
t _{rr}	Reverse recovery time	I _F = 1000A, dI _{RR} /dt =100A/μs T _{case} =150°C, V _R =100V	5.0		μS
Qs	Total stored charge		-	800	μC
I _{rr}	Peak reverse recovery current			250	Α
K	Softness Factor		1.6	-	-
V _{TO}	Threshold voltage	At T _{vj} = 150°C	-	1.1	V
r _T	Slope resistance	At T _{vj} =150°C	-	0.5	mΩ
V_{FRM}	Forward recovery voltage	Di/dt = 1000A/us, T _j = 125°C			V

DEFINITION OF K FACTOR AND $\mathbf{Q}_{\mathsf{RA1}}$



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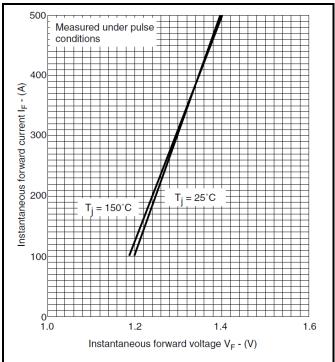


Fig.2 Maximum (limit) on-state characteristics

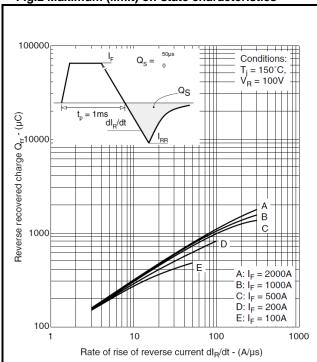


Fig.4 Recovered charge

Fig.3 Maximum (limit) on-state characteristics

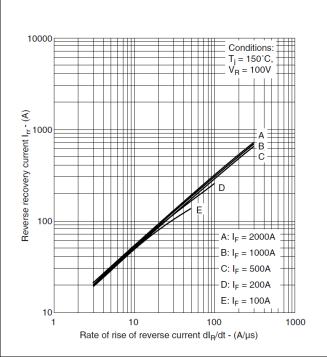


Fig.5 Typical reverse recovery current



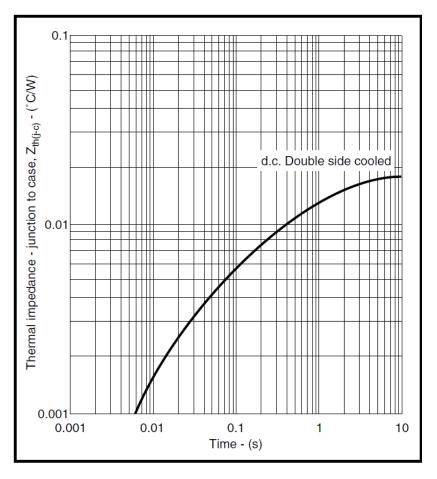
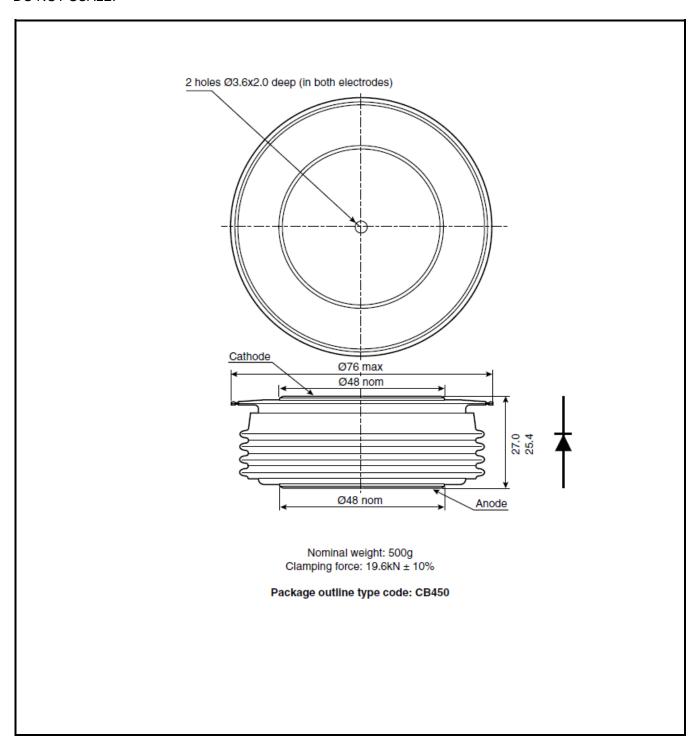


Fig.6 Maximum (limit) transient thermal impedance- junction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note: Some packages may be supplied with gate and or tags.



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HEADQUARTERS OPERATIONS

DYNEX SEMICONDUCTOR LIMITED
Doddington Road, Lincoln, Lincolnshire, LN6 3LF

United Kingdom.

No Annotation:

Phone: +44 (0) 1522 500500 Fax: +44 (0) 1522 500550 Web: http://www.dynexsemi.com

CUSTOMER SERVICE

Phone: +44 (0) 1522 502753 / 502901 Fax: +44 (0) 1522 500020

e-mail: power_solutions@dynexsemi.com

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